



# Methane-fueled thin film micro-solid oxide fuel cells with nanoporous palladium anodes

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## ABSTRACT

Methane-fueled thin film micro-solid oxide fuel cells ( $\mu$ SOFs) based on palladium (Pd) anodes are discussed in this article. The  $\mu$ SOFs are composed of porous platinum (Pt) cathodes, 8 mol.% yttria-stabilized zirconia (YSZ) ultrathin electrolytes, and Pd anodes – specifically, a Pt/YSZ/Pd heterostructure synthesized by physical vapor deposition. The Pt/YSZ/Pd  $\mu$ SOFs exhibit a power density of  $385 \text{ mW cm}^{-2}$  and an open circuit voltage of 0.77 V at  $550^\circ\text{C}$ . A detailed study on synthesis, microstructure and functional properties of the nanoporous Pd films is presented. Possible anodic methane reactions, carbon deposition on Pd anodes, and carbon suppression approaches are discussed. The results are of potential relevance to advancing low temperature micro-fuel cell technology using hydrocarbon fuels.

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## 1. Introduction

Fuel flexibility is considered to be a key advantage of solid oxide fuel cells (SOFCs) [1,2]. In addition to hydrogen ( $\text{H}_2$ ), hydrocarbons ( $\text{C}_n\text{H}_{2n+2}$ ), natural gas, biogases, biofuels, and military logistic fuels may also be used to operate SOFCs [3]. The use of pure hydrogen is challenging to implement on a large scale. Moreover, majority of  $\text{H}_2$  produced is via steam reforming of methane ( $\text{CH}_4$ ), increasing the cost and lowering the overall energy efficiency of  $\text{H}_2$  fuels. Hydrocarbons ( $\text{C}_n\text{H}_{2n+2}$ ) and natural gas are widely available and some biofuels such as butanol and Fischer–Tropsch fuels could potentially be distributed via existing automobile gasoline infrastructure [4]. As a result, SOFCs operated by these  $\text{H}_2$ -alternative fuels are highly desirable and have emerged as a significant research topic.

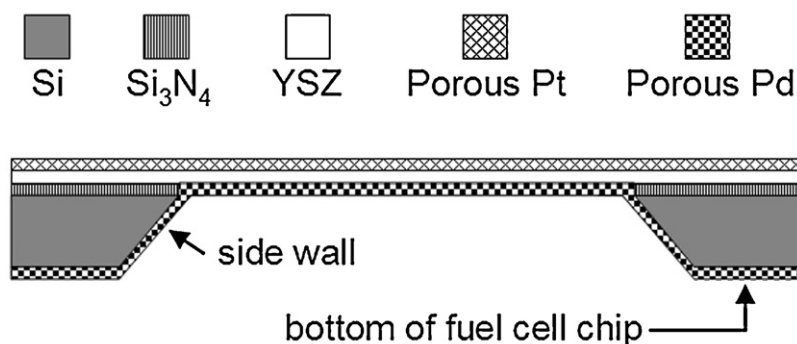
Among  $\text{H}_2$ -alternative fuels, hydrocarbons such as methane and n-butane receive substantial research attention and have been successfully demonstrated to operate SOFCs [1,5–10]. For example, a methane-fueled SOFC, which used  $\sim 1 \text{ mm}$  thick Ni-YSZ anodes, reported by Lin et al. [10] exhibited a peak power density ( $P_{\text{max}}$ ) of  $200 \text{ mW cm}^{-2}$  and an open circuit voltage (OCV) of 1.05 V at  $600^\circ\text{C}$ . A critical challenge in methane-fueled SOFCs is lowering their operating temperatures while maintaining acceptable performance. In this report, we will address this challenge based on the high-performance  $\mu$ SOF platform that has been developed in recent years [11–16]. Such  $\mu$ SOFs have been demonstrated to achieve

$>1000 \text{ mW cm}^{-2}$  power density at  $500^\circ\text{C}$  [17] and  $861 \text{ mW cm}^{-2}$  at  $450^\circ\text{C}$  [18], in part due to high flux of electron-generating  $\text{O}^{2-}$  transport through ultrathin electrolytes. As discussed in Ref. [19], high  $\text{O}^{2-}$  flux towards the anode of direct hydrocarbon-fueled  $\mu$ SOFs is critical to minimize carbon deposition (coking).

We chose methane ( $\text{CH}_4$ ) as the fuel in this study because it is among the most widely studied hydrocarbons. It has the following advantages over other higher hydrocarbons: (i) the smallest carbon footprint due to the lowest C/ $\text{H}_2$  ratio; (ii) it is abundant and can be produced from oil drilling, coal mining, and biomass decomposition; (iii) it constitutes  $\sim 85\%$  of natural gas and more than 50% of typical biogases, both of which are very promising  $\text{H}_2$ -alternative fuels for SOFCs. Moreover, methane gas is used to produce methanol [20], which is an important liquid fuel. Therefore, methane is a very appealing  $\text{H}_2$ -alternative fuel for SOFCs.

Since methane is a stable hydrocarbon [21], a highly active anode catalyst towards  $\text{CH}_4$  oxidation or cracking is critical to realize methane-fueled SOFCs at low temperatures. Catalytic systems for complete oxidation ( $\text{CH}_4 + 2\text{O}_2 \rightarrow \text{CO}_2 + 2\text{H}_2\text{O}$ , methane combustion) [22], partial oxidation ( $2\text{CH}_4 + \text{O}_2 \rightarrow 2\text{CO} + 4\text{H}_2$ ) [23], steam reforming ( $\text{CH}_4 + \text{H}_2\text{O} \rightarrow \text{CO} + 3\text{H}_2$ ) [20], and catalytic cracking ( $\text{CH}_4 \rightarrow \text{C} + 2\text{H}_2$ ) [20] of methane for  $\text{H}_2$  or synthesis gas production have been studied. Most studies show that Pd supported by redox-capable oxides [24–27] exhibits excellent low temperature catalytic activity in the aforementioned methane reactions; the redox-capable oxides include ceria [24,28], zirconia [29–31], and ceria-zirconia [32]. For example, Pd/zirconia systems can completely convert methane via complete oxidation of methane at  $T < 500^\circ\text{C}$  [31] and convert 90% of methane to synthesis gas via

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**Fig. 1.** A schematic cross-sectional view of a  $\mu$ SOFC. Pd thin films cover whole anode side of the  $\mu$ SOFC, including fuel cell anode, side walls of etched Si wells, and the bottom of fuel cells chips.

partial oxidation of methane at  $T = 630^\circ\text{C}$  [21]; while in contrast, without any catalyst, temperature has to reach  $\sim 800^\circ\text{C}$  to thermally decompose 95% of methane ( $\text{CH}_4 \rightarrow \text{C} + 2\text{H}_2$ ) [21].

It is worth noting that, when exposed to ambient air ( $p_{\text{O}_2} = 0.21 \text{ atm}$ ), Pd bulk oxidizes to PdO in  $300\text{--}400^\circ\text{C}$  range with a change in unit cell volume and PdO is stable in ambient air up to  $\sim 700^\circ\text{C}$ . The active lattice and electronic structures of Pd and PdO in this temperature range is essential to understand the behavior of complete oxidation of methane, for which methane conversion typically starts to take place at  $300^\circ\text{C}$  and achieves a  $>90\%$  rate at temperatures as low as  $400^\circ\text{C}$  [31]. It is generally accepted that the presence of PdO on Pd particles or films is essential to achieve a high catalytic reactivity towards methane [22,33,34].

The fact that both ceria and zirconia are typical SOFC electrolytes or part of electrode matrices and the temperatures for high conversion rate is in the range of interest to  $\mu$ SOFCs, as well as good thermal expansion coefficient matching between Pd ( $\sim 11.5 \times 10^{-6} \text{ K}^{-1}$ ) and YSZ ( $\sim 10.1 \times 10^{-6} \text{ K}^{-1}$ ) [35,36], indicate Pd would be an appealing anode material to explore for methane-fueled  $\mu$ SOFCs. Although there have been attempts to incorporate Pd as anode materials in conventional SOFCs [37–41], to the best of authors' knowledge, this is the first report on such efforts with thin film  $\mu$ SOFCs operated in methane.

Our objective is to explore high-performance methane-fueled  $\mu$ SOFCs based on Pd anodes. The electrolytes and cathodes are thin film YSZ and Pt, respectively. Since Pd has never been discussed before in thin film  $\mu$ SOFCs, emphasis topics in this paper are on the synthesis and understanding of Pd thin films and on the performance of methane-fueled  $\mu$ SOFCs based on Pd anodes. Our results show that a peak power density of  $385 \text{ mW cm}^{-2}$  and an open circuit voltage of  $0.77 \text{ eV}$  can be achieved at  $550^\circ\text{C}$ . Carbon deposition, a concern for hydrocarbon-fueled SOFCs, was observed and will be discussed.

## 2. Experimental details

Deposition of 8 mol.% yttria-doped zirconia (YSZ) films were performed in 5 mTorr Ar plasma and at 100 W target power by radio-frequency sputtering from a stoichiometric target. Both platinum (Pt) and palladium (Pd) thin films were deposited by direct-current sputtering in 75 mTorr Ar and at 250 W target power. Substrates were not heated during these depositions. Nominal deposition rates of as-deposited YSZ, Pt, and Pd thin films on single crystalline (100) YSZ (sc-YSZ) substrates were  $\sim 1.5$ ,  $\sim 5.4$ , and  $\sim 3.3 \text{ nm min}^{-1}$ , respectively, estimated from X-ray reflectivity. The same deposition chamber was used to anneal Pd in vacuum, with pressures lower than  $5 \times 10^{-6} \text{ mTorr}$ . Grazing incidence (at  $1^\circ$  omega) and theta – 2 theta ( $\theta - 2\theta$ ) X-ray diffraction (XRD) were performed with a Scintag 2000 diffractometer using  $\text{Cu K}\alpha$  radi-

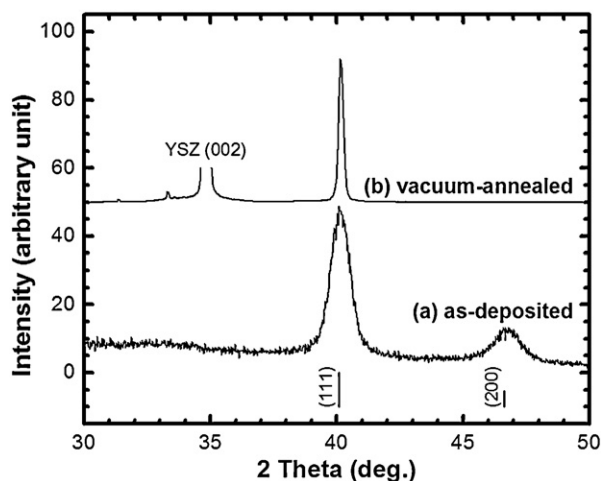
ation. Surface morphology was investigated by Carl Zeiss Ultra 55 field emission scanning electron microscopy (SEM). Lateral electrical conductivity of as-deposited Pd thin films on sc-YSZ substrates at room temperature were measured by a Creative Design Engineering ResMap 168 four-point probe resistivity mapping system. High temperature lateral electrical conductivity measurement of as-deposited Pd thin films on sc-YSZ substrates were performed using the same electrode configuration and procedure detailed in Ref. [42] and fuel cell testing system described in Ref. [16].

$\mu$ SOFC membranes were fabricated on  $\text{Si}_3\text{N}_4$ -coated Si chips with dimensions of  $10 \text{ mm} \times 10 \text{ mm} \times 0.5 \text{ mm}$ . The fabrication procedure was as follows: (i)  $\text{Si}_3\text{N}_4$  thin films were patterned by photolithography and then removed by reactive ion etching (RIE); (ii) 30% KOH was used to etch through Si, forming Si wells, to release free standing  $\text{Si}_3\text{N}_4$  thin films from Si; (iii) YSZ and then Pt were deposited onto the cathode side; (iv) RIE was used to remove  $\text{Si}_3\text{N}_4$  on the anode side to release Pt/YSZ thin films; (v) Pd was deposited onto the anode side, yielding Pt/YSZ/Pd  $\mu$ SOFC membranes. The width of square  $\mu$ SOFC membranes was in  $150\text{--}160 \mu\text{m}$  range, as measured by SEM. Fig. 1 shows a schematic cross-sectional view of a  $\mu$ SOFC. Note that side walls of etched Si wells and the bottom of fuel cell chips were also coated with Pd during deposition of Pd anode. Detailed fabrication considerations and procedures have been discussed in Refs. [43,44]. During fuel cell measurements, humidified pure  $\text{CH}_4$  at a flow rate of  $200 \text{ ml min}^{-1}$  or 5%  $\text{H}_2$  forming gases at a flow rates of  $100 \text{ ml min}^{-1}$  were fed to the anodes on the bottom of the chips while the cathodes were exposed to laboratory air.

## 3. Results and discussion

### 3.1. Pd thin films

To synthesize Pd thin films with suitable porosity for fuel cell operation, Pd thin films of different thicknesses were deposited on sc-YSZ substrates at 75 mTorr, which is a similar pressure range as porous Pt anode deposition in previous works [43,44]. Fig. 2(a) shows a XRD pattern of a 66 nm thick as-deposited Pd thin film. Powder diffraction of polycrystalline Pd from JCPDS 03-065-2867 is displayed on the bottom of Fig. 2; in which Pd (111) and (200) peaks are located at  $40.11^\circ$  and  $46.65^\circ 2\theta$ , respectively, and intensity ratio of Pd (111) to (200) peaks is  $\sim 0.45$ . Referring to JCPDS 03-065-2867, as-deposited Pd thin films were in cubic phase with a preferred orientation of (111). The intensity ratio of Pd (111) to (200) peaks in Fig. 2(a) is  $\sim 0.21$ . The relatively large full width at half maximum (FWHM),  $\sim 0.9^\circ$ , of (111) peaks indicated nanocrystallinity of as-deposited Pd thin films. Room temperature electrical conductivity of the as-deposited Pd thin film was in  $23\text{--}28 \times 10^3 \text{ S cm}^{-1}$  range. In contrast, conductivity of bulk Pd is  $\sim 100 \times 10^3 \text{ S cm}^{-1}$ . The difference is due to nanocrystalline mor-



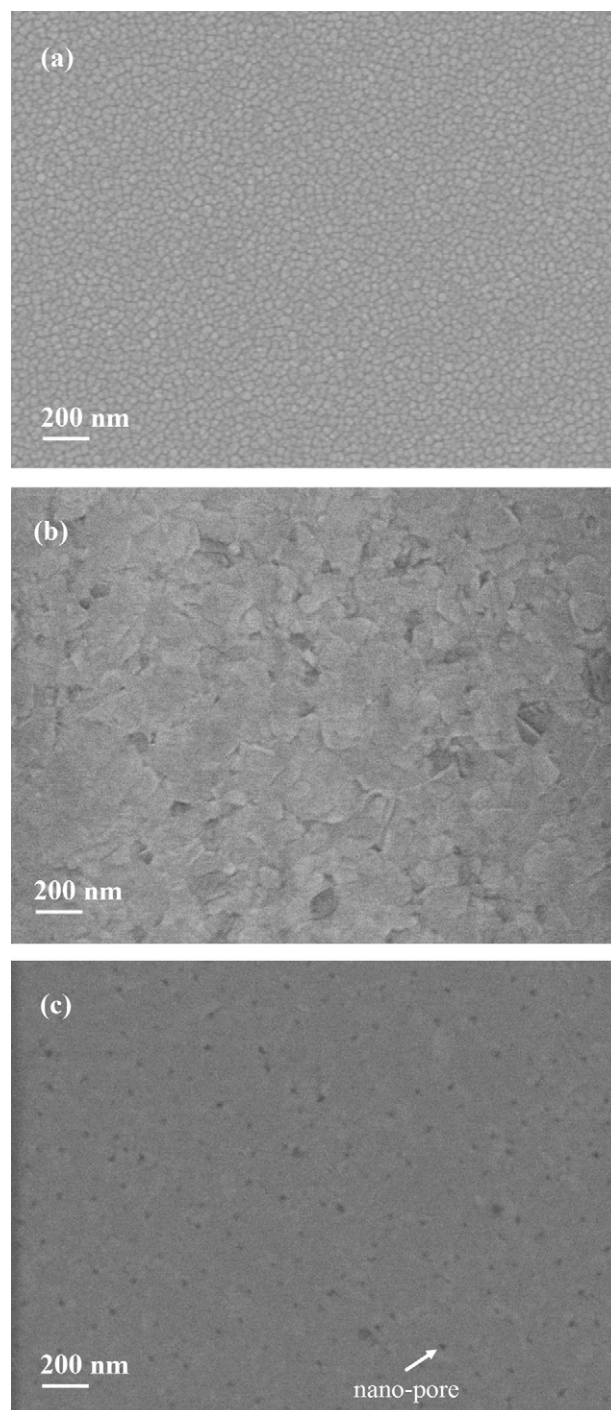
**Fig. 2.** XRD of 66 nm thick Pd thin films that were (a) as-deposited and (b) annealed in vacuum at 550 °C for 1 h. The substrates were single crystalline YSZ (1 0 0). Position and relative intensity of Pd (1 1 1) and (2 0 0) XRD peaks (JCPDS 03-065-2867) are also plotted. (a) was taken at a grazing incidence angle of 1° omega; while (b) was taken using  $\theta - 2\theta$  scan.

phology [45] and loosely packed Pd nano-grains. As seen in Fig. 3(a), the nominal grain size for a 66 nm thick as-deposited Pd thin film is  $35 \pm 5$  nm. After annealing in vacuum at 550 °C for 1 h (referred to as vacuum-annealed hence-forth), three changes were noted. First, Pd thin films became (1 1 1)-textured. The XRD pattern in Fig. 2 for an annealed 66 nm thick Pd thin film was obtained using  $\theta - 2\theta$  scan. For better comparison of Pd XRD peaks, YSZ (0 0 2) peak at  $35.87^\circ 2\theta$  from Cu  $K_\alpha$  radiation in Fig. 2 was truncated. A small peak at  $\sim 34^\circ 2\theta$  was YSZ (0 0 2) from Cu  $K_{\beta 1}$  radiation. Similar orientation trends have also been observed for Pt thin films on sc-YSZ (1 0 0) substrates [46,47] and the lattice misfit is accommodated by twinning of Pt domains. Since Pd and Pt are both cubic and have similar lattice constants (Pd: 0.389 nm; Pt: 0.392 nm) and several other physical properties, it is possible that the rationale for explaining behavior of Pt may be extended to Pd.

Second, significant microstructural changes and grain growth was observed (see Fig. 3). The grain size in vacuum-annealed Pd thin films varied from tens to hundreds of nm and their fish scale-like grain morphology is similar to the (1 1 1)-textured Pt thin films on sc-YSZ (1 0 0) substrates [46]. The larger grain size was also manifested in the FWHM of Pd (1 1 1) peak shown in Fig. 2, which changes from  $0.9^\circ$  to  $0.2^\circ$  after the annealing. The grain size increase suggest that mass transport of Pd in reducing environment is active at  $T < 550^\circ\text{C}$ . Third, there was an increase in electrical conductivity of Pd thin films after annealing, as seen in Fig. 4. For Pd thin films thicker than 56 nm, the conductivity increased by three fold and reached up to 75% of bulk ( $100 \times 10^3 \text{ S cm}^{-1}$ ) after annealing. This is attributed to the grain growth, which reduces grain boundary electron scattering [45], and denser microstructures. As demonstrated in Fig. 3(c), the thickness dependence of electrical conductivity for thinner Pd thin films is probably related to their nanoporous morphology and different granular structures.

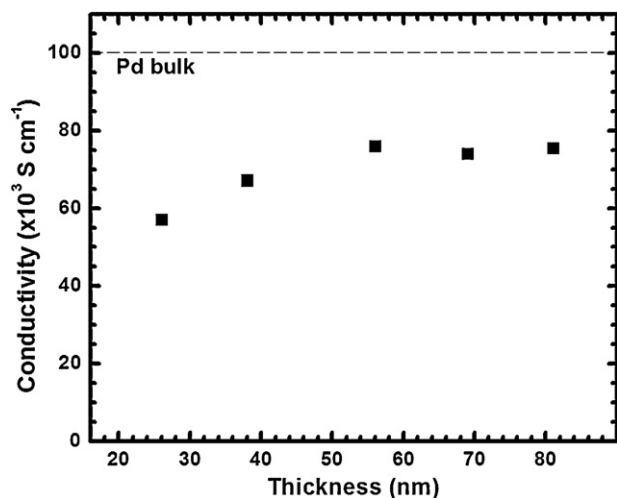
### 3.2. $\mu\text{SOFCs}$ with Pd anodes

It is crucial to control the thickness of Pd anodes. If an anode film is too thin, microstructure will be unstable at operating temperatures and hence performance will degrade quickly; if an anode film is too thick, there will be no porosity to facilitate anodic reaction and hence the fuel cell will have no performance at all. The conductivity (Fig. 4) and SEM (Fig. 3) results suggest that, when thickness is less than  $\sim 56$  nm, Pd thin films possess slightly porous microstructure



**Fig. 3.** SEM images of 66 nm thick as-deposited Pd thin films that were (a) as-deposited and (b) annealed annealing in vacuum at 550 °C for 1 h. (c) SEM image of a 26 nm thick Pd thin film after annealing in vacuum at 550 °C for 1 h. The substrates were single crystalline YSZ (1 0 0).

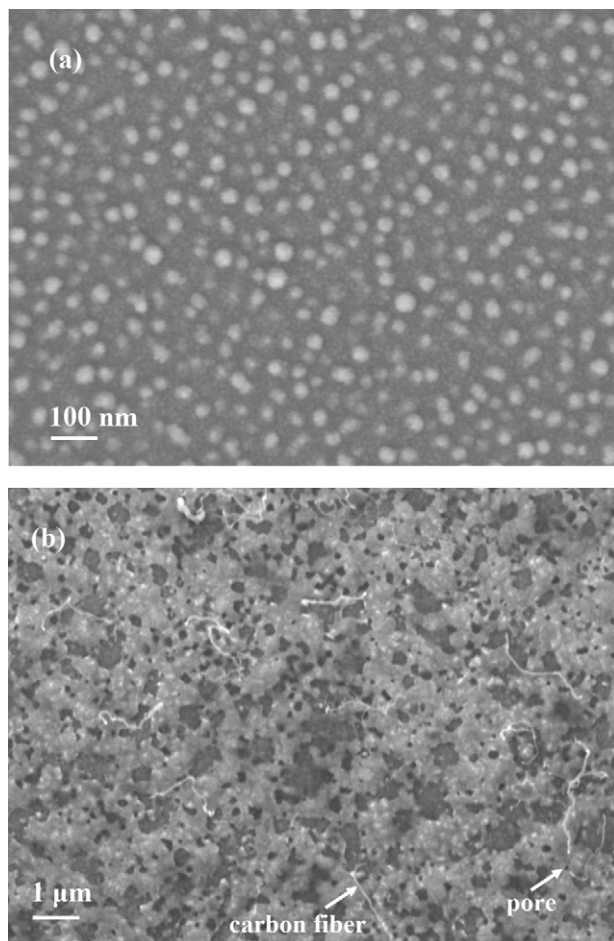
and good electrical conductivity in a high temperature reducing environment. Therefore, 50 nm was chosen as the thickness for Pd anode in the fuel cell studies. Fig. 5(a) shows surface morphology of a 50 nm thick as-deposited Pd anode on the bottom of an etched Si well. As seen, the Pd anode was composed of discrete Pd clusters, which is similar to the optimum surface morphology of Pt anode in the high performance  $\mu\text{SOFCs}$  reported in Ref. [17]. Such morphology, however, is different from the packed, well-connected Pd grains seen in the 66 nm thick Pd thin films on sc-YSZ substrates (Fig. 3(a)). The droplet-like morphology might be related to tem-



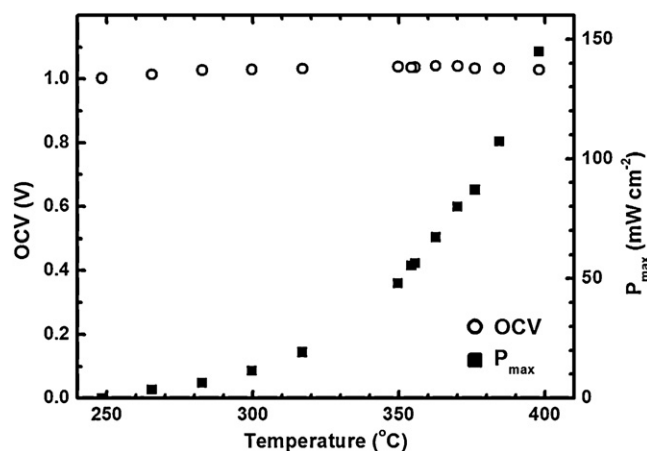
**Fig. 4.** Room temperature electrical conductivity for Pd thin films of varying thicknesses annealed in vacuum at 550 °C for 1 h. A horizontal dash line represents the typical conductivity ( $100 \times 10^3 \text{ S cm}^{-1}$ ) of bulk Pd.

perature and morphology of growth surface being different from that of single crystal substrates.

$\mu$ SOFCs with 70 nm thick porous Pt cathodes, 100 nm thick dense YSZ electrolyte, and 50 nm thick Pd anodes (referred to as Pt/YSZ/Pd  $\mu$ SOFCs) were fabricated following the procedure



**Fig. 5.** SEM images of 50 nm thick Pd anodes on a  $\mu$ SOFC membrane (a) before and (b) after fuel cell testing. Carbon fibers are indicated by white arrows. Pores that could be the roots of oxidized carbon fibers are also indicated by white arrows.

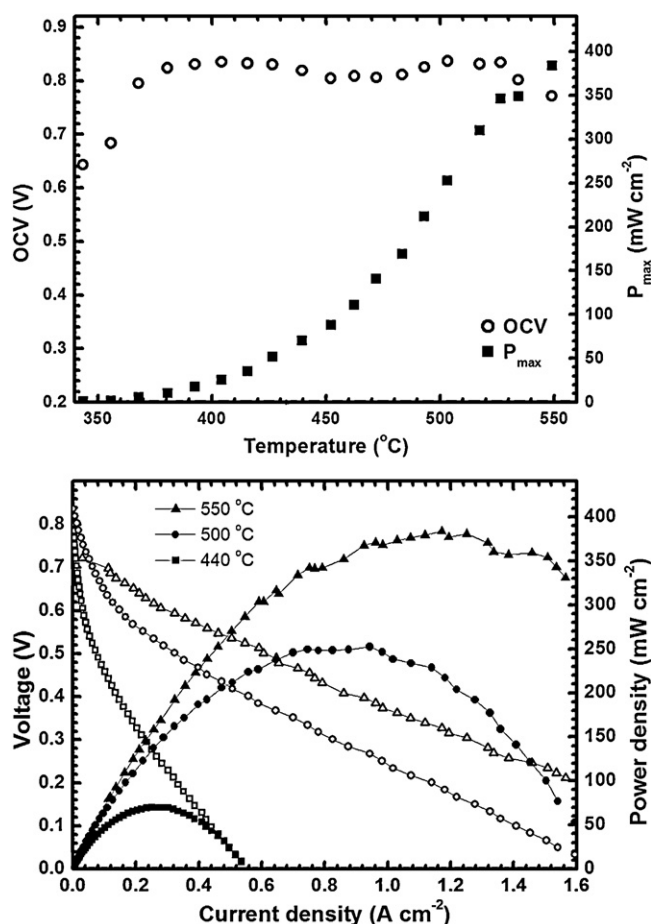


**Fig. 6.** Open circuit voltage (OCV,  $\circ$ ) and peak power density ( $P_{\text{max}}$ ,  $\blacksquare$ ) as a function of temperature for a  $\text{H}_2$ -fueled Pt/YSZ/Pd  $\mu$ SOFC.

described in Ref. [44]. To ensure appropriate choice of Pd thickness, a Pt/YSZ/Pd  $\mu$ SOFC was first tested up to 400 °C using  $\text{H}_2$  fuel. Fig. 6 shows its open circuit voltage (OCV) and peak power density ( $P_{\text{max}}$ ) as a function of temperature. As seen, OCV was stable and higher than 1.0 V in 250–400 °C range. At 400 °C, the  $\text{H}_2$ -fueled Pt/YSZ/Pd  $\mu$ SOFC exhibited  $P_{\text{max}} = 145 \text{ mW cm}^{-2}$  and OCV = 1.03 V. Such performance is  $\sim 50\%$  of that of recently reported  $\text{H}_2$ -fueled Pt/YSZ/Pt  $\mu$ SOFCs [17], which exhibited  $P_{\text{max}} = 300 \text{ mW cm}^{-2}$  and OCV = 1.0 V at 400 °C. The result further indicated that 50 nm is a suitable thickness for Pd anodes and its corresponding structure would evolve into a suitable porous morphology at temperature as low as 250 °C.

An identical Pt/YSZ/Pd  $\mu$ SOFC was then tested using  $\text{CH}_4$  fuel. Fig. 7(a) shows its temperature-dependent OCV and  $P_{\text{max}}$ . Methane was supplied before the fuel cell was heated for testing and until the tested  $\mu$ SOFC cooled down below  $\sim 100$  °C. As seen in Fig. 7(a), OCV stabilized at  $0.82 \pm 0.02 \text{ V}$  in 380–530 °C range.  $P_{\text{max}}$  and OCV reached  $200 \text{ mW cm}^{-2}$  and 0.84 V, respectively, at 500 °C and  $385 \text{ mW cm}^{-2}$  and 0.77 V, respectively, at 550 °C. Voltage and power density as a function of current density at 440 °C, 500 °C, and 550 °C are plotted in Fig. 7(b); when temperature increased from 440 °C to 500 °C, ohmic loss decreased apparently. Fig. 5(b) shows surface morphology of Pd anode after 5 h of fuel cell testing. As seen, a very small amount of carbon deposition in the form of fibers was observed. Small pores might be the roots of carbon fibers, which were oxidized ( $\text{C} + 2\text{O}^{2-} \rightarrow \text{CO}_2$ ) and removed from the anode at high temperatures during testing when supply of oxygen ions is abundant. We also observed carbon fibers on the side walls of etched Si wells, which were also coated with Pd during anode deposition. Carbon deposition on non-reactive regions of SOFC anodes has also been reported in the literature [48].

The observed carbon deposition on anode surface and side walls is likely formed via catalytic cracking of methane ( $\text{CH}_4 \rightarrow \text{C} + 2\text{H}_2$ ) on Pd anodes [6]. Note that complete oxidation [1,6] and partial oxidation [49] of methane are unlikely the dominant anodic reactions because the required critical  $\text{O}^{2-}/\text{CH}_4$  ratio [10] of  $\sim 0.5$  and  $\sim 1.5$ , respectively, for the reaction to dominate. These ratios are much higher than our testing conditions—namely, oversupply of  $\text{CH}_4$  and low flux of  $\text{O}^{2-}$  at low temperatures. The methane cracking products (C and  $\text{H}_2$ ) would then react with  $\text{O}^{2-}$  via carbon oxidation ( $\text{C} + \text{O}^{2-} \rightarrow \text{CO} + 2\text{e}^-$ ) and hydrogen oxidation ( $\text{H}_2 + \text{O}^{2-} \rightarrow \text{H}_2\text{O} + 2\text{e}^-$ ) reactions and produce electrons to external circuits. The corresponding ideal Nernst potentials with these two reactions at 450 °C are  $\sim 1.05$  and  $\sim 1.15 \text{ V}$  [10,50], both are higher than the measured OCV ( $0.82 \pm 0.02 \text{ V}$  in 380–530 °C range). We speculate that the discrepancy between measured and ideal



**Fig. 7.** (a) Open circuit voltage (OCV,  $\circ$ ) and peak power density ( $P_{\max}$ ,  $\blacksquare$ ) as a function temperature for a  $\text{CH}_4$ -fueled Pt/YSZ/Pd  $\mu\text{SOFC}$ . (b) Voltage (open symbols) and power density (solid symbols) as a function of current density at 440 °C (square symbols), 500 °C (circular symbols), and 550 °C (triangular symbols) for a  $\text{CH}_4$ -fueled Pt/YSZ/Pd  $\mu\text{SOFC}$ .

OCV is related to carbon deposition. The carbon deposition on the Pd anode may block or impede hydrogen oxidation. The observed carbon deposition, which might delaminate Pd films [49], on the side walls of etched Si wells or on the bottom of nanoporous Pd-covered testing Si chips could also lead to voltage loss. Note that carbon deposition depends on the balance of  $\text{O}^{2-}$  flux and cracking efficiency, both increase with temperature, and could occur over a wide temperature range. Since cracking efficiency is higher at high temperatures, carbon deposition could rapidly degrade fuel cells if sufficient  $\text{O}^{2-}$  flux is not supplied at high temperatures [10,19,51]. Besides methane cracking, CO disproportionation ( $2\text{CO} \rightarrow \text{C} + \text{CO}_2$ ,  $\Delta H_{298} = -172.4 \text{ kJ mol}^{-1}$ ), CO reduction reaction ( $\text{CO} + \text{H}_2 \rightarrow \text{C} + \text{H}_2\text{O}$ ,  $\Delta H_{298} = -132.2 \text{ kJ mol}^{-1}$ ), and  $\text{CO}_2$  reduction reaction ( $\text{CO}_2 + 2\text{H}_2 \rightarrow \text{C} + 2\text{H}_2\text{O}$ ,  $\Delta H_{298} = -90.15 \text{ kJ mol}^{-1}$ ) could also lead to carbon deposition [19]. These reactions are exothermic and preferred at low temperatures.

To minimize carbon deposition, several approaches have been reported and could likely be implemented to further improve the methane-fueled  $\mu\text{SOFC}$ s reported here. First, ceria-based anodes have been demonstrated to suppress carbon deposition [1,6,7]. Second, increased partial pressure of  $\text{H}_2\text{O}$  could suppress carbon-generating CO and  $\text{CO}_2$  reduction reactions or remove carbon via  $\text{C} + \text{H}_2\text{O} \rightarrow \text{CO} + \text{H}_2$ ,  $\Delta H_{298} = 131.19 \text{ kJ mol}^{-1}$ , at high temperatures, as suggested in Ref. [52]. Third, precise control of  $\text{CH}_4$  supply to maintain a  $\text{O}^{2-}/\text{CH}_4$  ratio of  $\sim 1.0$  has been demonstrated to convert over 90% of  $\text{CH}_4$  into syn-

thesis gas with little carbon deposition via methane cracking [53].

#### 4. Conclusions

Functional methane-fueled thin film  $\mu\text{SOFC}$ s based on nanoporous Pd anode, YSZ electrolyte, and Pt cathode has been demonstrated. Nanocrystalline porous Pd thin films with good electrical conduction properties were synthesized by performing sputtering at high pressures and controlling their thicknesses in the vicinity of nominal grain size. The Pt/YSZ/Pd  $\mu\text{SOFC}$ s exhibit a peak power density of  $385 \text{ mW cm}^{-2}$  and an open circuit voltage of 0.77 V at 550 °C. Carbon deposition was observed and approaches to manage it have been discussed. The results presented in this manuscript could be relevant towards further advancing low temperature fuel-flexible solid oxide fuel cells using thin film components.

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